



#### 40V P-Channel Enhancement Mode MOSFET

Voltage

-40 V

Current

-3.1A

#### **Features**

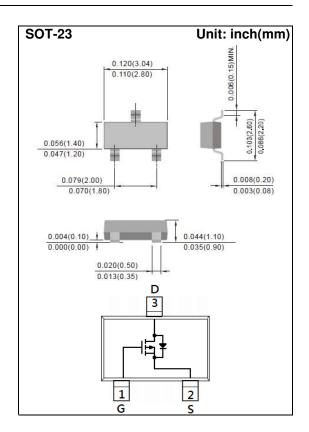
- $R_{DS(ON)}$ ,  $V_{GS}$ @-10V,  $I_{D}$ @-3.1A<88m $\Omega$
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-4.5V, I<sub>D</sub>@-2.6A<108mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-40	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current		I <sub>D</sub>	-3.1	_ A	
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	-12.4		
Power Dissipation	T <sub>a</sub> =25°C	$P_{D}$	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W	





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1.0	-1.5	-2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-3.1A	-	74	88	mΩ
		$V_{GS}$ =-4.5V, $I_{D}$ =-2.6A	-	88	108	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 5)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-20V, I <sub>D</sub> =-3.1A, V <sub>GS</sub> =-4.5V <sup>(Note 1,2)</sup>	-	6	-	nC
Gate-Source Charge	$Q_gs$		-	1.6	-	
Gate-Drain Charge	$Q_gd$		-	2.3	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	505	-	pF
Output Capacitance	Coss		-	48	-	
Reverse Transfer Capacitance	Crss		-	33	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =-20V, $I_{D}$ =-2.5A, $V_{GS}$ =-10V, $R_{G}$ =1 $\Omega$ (Note 1,2)	-	6	-	ns
Turn-On Rise Time	tr		-	35	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	18	-	
Turn-Off Fall Time	tf		_	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	,		-	-	-1.0	А
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	-0.82	-1.2	V
Reverse Recovery Time	trr	$V_{GS}$ =0V, $I_{S}$ =-2.5A $dI_{F}$ / $dt$ =100A/us	-	13	-	ns
Reverse Recovery Charge	Qrr		-	8.7	-	nC

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

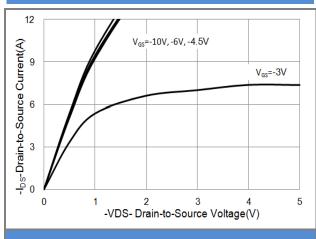


Fig.1 On-Region Characteristics

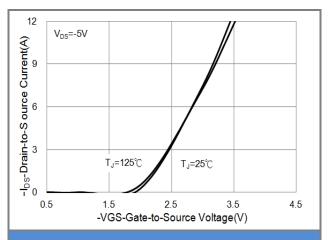


Fig.2 Transfer Characteristics

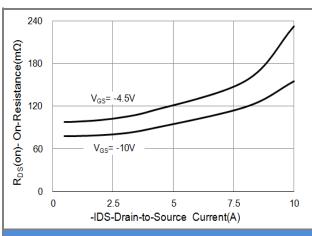


Fig.3 On-Resistance vs. Drain Current

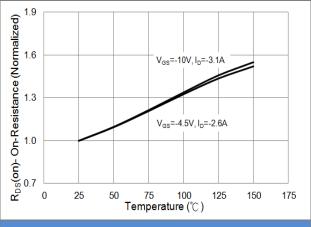
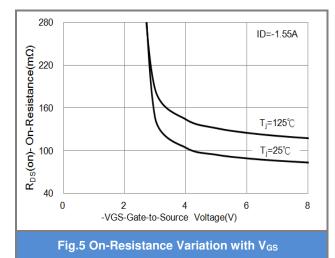
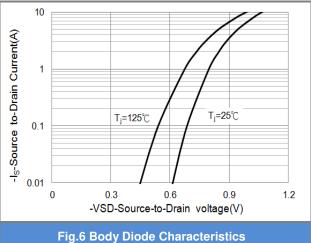


Fig.4 On-Resistance vs. Junction temperature









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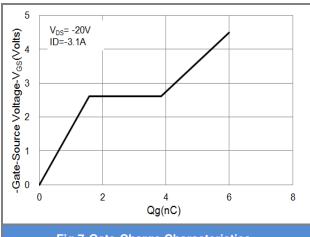
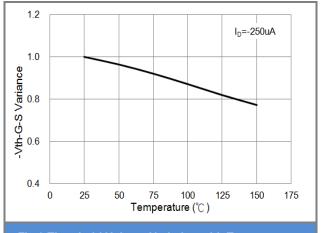


Fig.7 Gate-Charge Characteristics



**Fig.8 Threshold Voltage Variation with Temperature** 

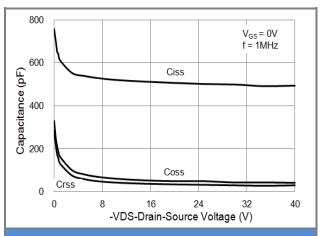


Fig.9 Capacitance vs. Drain-Source Voltage

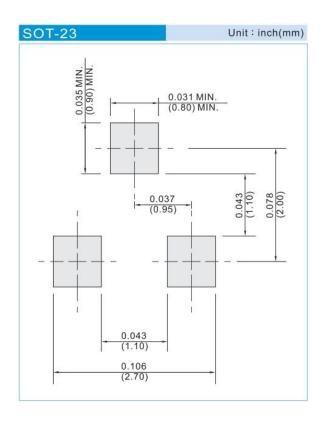




### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3441-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A41	Halogen free

### **Mounting Pad Layout**







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